Application Data Sheet

Application Information

Application Type:: Regular Subject Matter:: Utility

Title:: Trench MOSFET Having Implanted Drain-Drift

Region And Process For Manufacturing The Same

Attorney Docket Number:: SCX010-5D US

Request for Early Publication?:: No

Request for Non-Publication?:: No

Total Drawing Sheets:: 18

Small Entity?:: No

Petition Included?:: No

Secrecy Order in Parent Appl.?:: No

Applicant Information

Applicant Authority Type:: Inventor

Primary Citizenship Country:: US

Status:: Full Capacity

Given Name:: Mohamed

Middle Name:: N.

Family Name:: Darwish

Name Suffix::

City of Residence:: Campbell

State or Province of Residence:: California

Country of Residence:: US

Street of Mailing Address:: 675 Regas Drive

City of Mailing Address:: Campbell

State or Province of Mailing Address:: California

Country of Mailing Address:: US

Postal or Zip Code of mailing 95008

address::

Correspondence Information

Correspondence Customer Number::

34036

Representative Information

Representative Customer Number::	34036

Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	Divisional of	10/317,568	12/12/02
10/317,568	Continuation in part of	09/898,652	07/03/01

Assignee Information

Assignee Name::

Siliconix incorporated

Street of Mailing Address::

2201 Laurelwood Road

City of Mailing Address::

Campbell

State of Mailing Address::

California

Country of Mailing Address::

USA

Zip Code of Mailing Address::

95008